Reliability of Capacitors for DC-Link Applications – An Overview

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Abstract— DC-link capacitors are an important part in the majority of power electronic converters which contribute to cost, size and failure rate on a considerable scale. From capacitor users’ viewpoint, this paper presents a review on the improvement of reliability of DC-link in power electronic converters from two aspects: 1) reliability-oriented DC-link design solutions; 2) conditioning monitoring of DC-link capacitors during operation. Failure mechanisms, failure modes and lifetime models of capacitors suitable for the applications are also discussed as a basis to understand the physics-of-failure. This review serves to provide a clear picture of the state-of-the-art research in this area and to identify the corresponding challenges and future research directions for capacitors and their DC-link applications.

I. INTRODUCTION

DC-link capacitors are widely used in power converters to balance the instantaneous power difference between the input source and output load, and minimize voltage variation in the DC link. In some applications, they are also used to provide sufficient energy during the hold-up time. Fig. 1 shows the typical configurations of power electronic conversion systems with DC-link capacitors. Such configurations cover a wide range of power electronics applications, such as in wind turbines, photovoltaic systems, motor drives, electric vehicles and lighting systems. With more stringent reliability constrains brought by automotive, aerospace and energy industries, the design of DC links encounters the following challenges: a) capacitors are one kind of the stand-out components in terms of failure rate in field operation of power electronic systems [1]-[2]; b) cost reduction pressure from global competition dictates minimum design margin of capacitors without undue risk; c) capacitors are to be exposed to more harsh environments (e.g. high ambient temperature, high humidity, etc.) in emerging applications and d) constrains on volume and thermal dissipation of capacitors with the trends for high power density power electronic systems [3].

The efforts to overcome the above challenges can be divided into three categories: a) advance the capacitor technology with improved and pre-determined reliability built in, b) optimal DC-link design solutions based on the present capacitors to achieve proper robustness margin and cost-effectiveness, and c) implementations of condition monitoring to ensure reliable field operation and preventive maintenance. By taking the advantage of the progress in new dielectric materials and innovative manufacturing process, leading capacitor manufacturers have been continuously releasing new generations of products with improved reliability and cost performance. The proper application of these capacitors for specific DC-link design is equally important as the operating conditions (e.g. temperature, humidity, ripple current, voltage) could significantly influence the reliability of the capacitors. Compared to the first category, the latter two are more relevant from the power electronic designers’ perspective, which therefore will be reviewed in this paper. Moreover, the comparison of capacitors suitable for DC-link applications are given. The failure modes, failure mechanisms, corresponding critical stressors and lifetime models of them are also mapped. The challenges and opportunities for future research directions are finally addressed.

The work described in this paper was supported by the grant 12-131914 from the Danish Council for Independent Research, Denmark.
II. CAPACITORS FOR DC-LINK APPLICATIONS

Three types of capacitors are generally available for DC-link applications, which are the Aluminum Electrolytic Capacitors (Al-Caps), Metallized Polypropylene Film Capacitors (MPPF-Caps) and high capacitance Multi-Layer Ceramic Capacitors (MLC-Caps). The DC-link design requires the matching of available capacitor characteristics and parameters to the specific application needs under various environmental, electrical and mechanical stresses.

Fig. 2 shows a lumped model of capacitors. $C$, $R_s$ and $L_s$ are the capacitance, Equivalent Series Resistance (ESR), Equivalent Series Inductance (ESL), respectively. The Dissipation Factor (DF) is $\tan \delta = \omega R_s C$. $R_p$ is the insulation resistance. $D$ is the dielectric loss due to dielectric absorption and molecular polarization and $C_d$ is the inherent dielectric absorption [4]. The widely used simplified capacitor model is composed of $C$, $R_s$ and $L_s$. It should be noted that the values of them vary with temperature, voltage stress, frequency and time (i.e. operating conditions). The absence of the consideration into these variations may lead to improper analysis of the electrical stresses and thermal stresses, therefore, also many times unrealistic lifetime prediction.

The property of dielectric materials is a major factor that limits the performance of capacitors. Fig. 3 presents the relative permittivity (i.e. dielectric constant), continuous operational field strength and energy density limits of $Al_2O_3$, polypropylene and ceramics, which are the materials used in Al-Caps, MPPF-Caps and MLC-Caps, respectively [5]. It can be noted that $Al_2O_3$ has the highest energy density due to high field strength and high relative permittivity. The theoretical limit is in the range of 10 J/cm$^3$ and the commercial available one is about 2 J/cm$^3$. Ceramics could have much higher dielectric constant than $Al_2O_3$ and film, however, it suffers from low field strength, resulting in similar energy density as that of film.

The three type of capacitors therefore exhibit specific advantages and shortcomings. Fig. 4 compares their performance from different aspects in a qualitative way. Al-Caps could achieve the highest energy density and lowest cost per Joule, however, with relatively high ESRs, low ripple current ratings, and wear out issue due to evaporation of electrolyte. MLC-Caps have smaller size, wider frequency range, and higher operating temperatures up to 200°C. However, they suffer from higher cost and mechanical sensitivity. The recent release of CeraLink series ceramic capacitors [6] is of interest to extend the scope of MLC-Caps for DC-link applications. It is based on a new ceramic materials of antiferroelectric behavior and strong positive bias effect (i.e. capacitance versus voltage stress). MPPF-Caps provide a well-balanced performance for high voltage applications (e.g. above 500 V) in terms of cost and ESR, capacitance, ripple current and reliability. Nevertheless, they have the shortcomings of large volume and moderate upper operating temperature.

The DC-link applications can be classified into high ripple current ones and low ripple current ones. The ripple current capability of the three types of capacitors is approximately proportional to their capacitance values as shown in Fig. 5. $C_1$ is defined as the minimum required capacitance value to fulfill the voltage ripple specification. For low ripple current applications, capacitors with a total capacitance no less than $C_1$ are to be selected by both Al-Caps solution and MPPF-Caps solution. For high ripple current applications, the Al-Caps with capacitance of $C_1$ could not sustain the high ripple current stress due to low $A/\mu F$. Therefore, the required capacitance is increased to $C_2$ by Al-Caps solution while the one by MPPF-Caps solution is $C_1$. In terms of ripple current (i.e. $$/A$$), the cost of MPPF-Caps is about 1/3 of that of Al-Caps [7]. It implies the possibility to achieve a lower cost, higher power density DC-link design with MPPF-Caps in high ripple current applications, like the case in electric vehicles [8].

![Fig. 2. A simplified lumped model of capacitors.](image-url)

![Fig. 3. Energy storage density for various dielectrics (BOPP: Biaxial Oriented Polypropylene, which is the preferred film material for capacitors rated above about 250 V) [5].](image-url)

![Fig. 4. Performance comparisons of the three main types of capacitors for DC-link applications.](image-url)
III. FAILURE AND LIFETIME OF DC-LINK CAPACITORS

A. Failure Modes, Failure Mechanisms and Critical Stressors

DC-link capacitors could fail due to intrinsic and extrinsic factors, such as design defect, material wear out, operating temperature, voltage, current, moisture and mechanical stress, and so on. Generally, the failure can be divided into catastrophic failure due to single-event overstress and wear out failure due to the long time degradation of capacitors. The major failure mechanisms have been presented in [9]-[12] for Al-Caps, [13]-[17] for MPPF-Caps and [18]-[20] for MLC-Caps. Based on these prior-art research results, Table I gives a systematical summary of the failure modes, failure mechanisms and corresponding critical stressors of the three types of capacitors.

Table II shows the comparison of failure and self-healing capability of Al-Caps, MPPF-Caps and MLC-Caps. Electrolyte vaporization is the major wear out mechanism of small size Al-Caps (e.g. snap-in type) due to their relatively high ESR and limited heat dissipation surface. For large size Al-Caps, the wear out lifetime is dominantly determined by the increase of leakage current, which is relevant with the electrochemical reaction of oxide layer [21]. The most important reliability feature of MPPF-Caps is their self-healing capability [15]-[16]. Initial dielectric breakdowns (e.g. due to overvoltage) at local weak points of a MPPF-Cap will be cleared and the capacitor regains its full ability except for a negligible capacitance reduction. With the increase of these isolated weak points, the capacitance of the capacitor is gradually reduced to reach the end-of-life. The film layer in MPPF-Caps are in the order of 10-50 nm which are therefore susceptible to corrosion due to the ingress of atmospheric moisture. In [22], the corrosion mechanism is well studied. Figs. 6(a) and (b) shows the corrosion of the metallized layers of a degraded film capacitor located in the outer turns and inner turns of the capacitor roll, respectively. It reveals that severe corrosion occurs at the outer layers resulting in the separation of metal film from heavy edge and therefore the reduction of capacitance. The corrosion in the inner layers is less advanced as it is less open to the ingress of moisture. Unlike the dielectric materials of Al-Caps and MPPF-Caps,

![Fig. 5. Capacitance requirement of low ripple current applications and high ripple current applications.](image)

<table>
<thead>
<tr>
<th>Cap. type</th>
<th>Failure modes</th>
<th>Critical failure mechanisms</th>
<th>Critical stressors</th>
</tr>
</thead>
<tbody>
<tr>
<td>Al-Caps</td>
<td>Open circuit</td>
<td>Self-healing dielectric breakdown</td>
<td>$V_C$, $T_a$, $i_C$</td>
</tr>
<tr>
<td></td>
<td>Short circuit</td>
<td>Dielectric breakdown of oxide layer</td>
<td>$V_C$, $T_a$, $i_C$</td>
</tr>
<tr>
<td></td>
<td>Wear out: electrical parameter drift (C, ESR, tanδ, $i_{LC}$, $R_p$)</td>
<td>Electrolyte vaporization</td>
<td>$T_a$, $i_C$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>Electrochemical reaction (e.g. degradation of oxide layer, anode foil capacitance drop)</td>
<td>$V_C$</td>
</tr>
<tr>
<td>MPPF-Caps</td>
<td>Open circuit (typical)</td>
<td>Self-healing dielectric breakdown</td>
<td>$V_C$, $T_a$, $dV_C/dt$</td>
</tr>
<tr>
<td></td>
<td>Short circuit (with resistance)</td>
<td>Dielectric film breakdown</td>
<td>$V_C$, $dV_C/dt$</td>
</tr>
<tr>
<td></td>
<td>Wear out: electrical parameter drift (C, ESR, tanδ, $i_{LC}$, $R_p$)</td>
<td>Dielectric loss</td>
<td>$V_C$, $T_a$, $i_C$, humidity</td>
</tr>
<tr>
<td>MLC-Caps</td>
<td>Short circuit (typical)</td>
<td>Dielectric breakdown</td>
<td>$V_C$, $T_a$, $i_C$</td>
</tr>
<tr>
<td></td>
<td>Wear out: electrical parameter drift (C, ESR, tanδ, $i_{LC}$, $R_p$)</td>
<td>Oxide vacancy migration; dielectric puncture; insulation degradation; micro-crack within ceramic</td>
<td>$V_C$, $T_a$, $i_C$, vibration</td>
</tr>
</tbody>
</table>

$V_C$-capacitor voltage stress, $i_C$-capacitor ripple current stress, $i_{LC}$-leakage current, $T_a$-ambient temperature.
TABLE II: COMPARISONS OF FAILURE AND SELF-HEALING CAPABILITY OF THE THREE TYPES OF CAPACITORS.

<table>
<thead>
<tr>
<th></th>
<th>Al-Caps</th>
<th>MPPF-Caps</th>
<th>MLCC-Caps</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Dominant failure modes</strong></td>
<td>wear out</td>
<td>open circuit</td>
<td>short circuit</td>
</tr>
<tr>
<td><strong>Dominant failure mechanisms</strong></td>
<td>electrolyte vaporization; electrochemical reaction</td>
<td>moisture corrosion; dielectric loss</td>
<td>insulation degradation; flex cracking</td>
</tr>
<tr>
<td><strong>Most critical stressors</strong></td>
<td>$T_a, V_c, i_C$</td>
<td>$T_a, V_c, V_h$</td>
<td>$T_a, V_c, V_h, V_v$</td>
</tr>
<tr>
<td><strong>Self-healing capability</strong></td>
<td>moderate</td>
<td>good</td>
<td>no</td>
</tr>
</tbody>
</table>

In [23], it has been shown that a modern MLC-Cap could wear out within 10 years due to increasing miniaturization through the increase of the number of layers. Moreover, the failure of MLCC-Caps may induce severe consequences to power converters due to the short circuit failure mode. The dominant failure causes of MLCC-Caps are insulation degradation and flex cracking. Insulation degradation due to the decrease of the dielectric layer thickness results in increased leakage currents. Under high voltage and high temperature conditions, Avalanche BreakDown (ABD) and Thermal RunAway (TRA) could occur, respectively. Fig. 7 shows a study in [18] on the leakage current characteristics of a MLC-Cap with ABD and TRA failure. ABD features with an abrupt burst of current leading to an immediate breakdown, while TRA exhibits a more gradual increase of leakage current.

**B. Lifetime Models of DC-Link Capacitors**

Lifetime models are important for lifetime prediction, online condition monitoring and benchmark of different capacitor solutions. The most widely used empirical model for capacitors is shown in (1) which describes the influence of temperature and voltage stress.

$$L = L_0 \times \left( \frac{V}{V_0} \right)^n \times \exp \left( \frac{E_a}{K_B T} \left( \frac{1}{T} - \frac{1}{T_0} \right) \right)$$

where $L$ and $L_0$ are the lifetime under the use condition and testing condition, respectively. $V$ and $V_0$ are the voltage at use condition and test condition, respectively. $T$ and $T_0$ are the temperature in Kelvin at use condition and test condition, respectively. $E_a$ is the activation energy, $K_B$ is Boltzmann’s constant (8.62×10^-5 eV/K), and $n$ is the voltage stress exponent. Therefore, the values of $E_a$ and $n$ are the key parameters to be determined in the above model.

In [24], the $E_a$ and $n$ are found to be 1.19 and 2.46, respectively, for high dielectric constant ceramic capacitors. In [23], the ranges of $E_a$ and $n$ for MLCC-Caps are 1.3 – 1.5 and 1.5 – 7, respectively. The large discrepancies could be attributed to the ceramic materials, dielectric layer thickness, testing conditions, etc. With the trend for smaller size and thinner dielectric layer, the MLCC-Caps will be more sensitive to the voltage stress, implying a higher value of $n$. Moreover, under different testing voltages, the value of $n$ might be different as discussed in [25].

For Al-Caps and film capacitors, a simplified model from (1) is popularly applied as follows:

$$L = L_0 \times \left( \frac{V}{V_0} \right)^n \times 2^{E_a - T \ln \frac{T_0}{T}}$$

The derivation of (2) from (1) is discussed in [26]. The model presented by (2) is corresponding to a specific case of (1) when $E_a = 0.94$ eV and $T_0$ and $T$ are substituted by 398 K. For MPPF-Caps, the exponent $n$ is from around 7 to 9.4 used by leading capacitor manufacturers [27]. For Al-Caps, the value of $n$ typically varies from 3 to 5 [28]. However, the
voltage dependency of lifetime for Al-Caps quite depends on the voltage stress level. In [10], instead of a power law relationship, a linear equation is found to be more suitable to describe the impact of voltage stress. To obtain the physical explanations of the lifetime model variants from different capacitor manufacturers, a generic model is derived in [29] as follows:

\[
\frac{V_s}{V_0} \times \exp\left(\frac{E_a}{K_b} \left(\frac{1}{T_0} - \frac{1}{T}\right)\right) \quad \text{(low voltage stress)}
\]

\[
\frac{V}{V_0} \times \exp\left(\frac{E_a}{K_b} \left(\frac{1}{T_0} - \frac{1}{T}\right)\right) \quad \text{(medium voltage stress)}
\]

\[
\exp\left(a_0 (V_0 - V)\right) \times \exp\left(\frac{E_a - a_0 V}{K_a T} - \frac{E_a - a_0 V}{K_a T_0}\right) \quad \text{(high voltage stress)}
\]

where \(a_0\) and \(a_1\) are constants describing the voltage and temperature dependency of \(E_a\). \(E_{a0}\) is the activation energy under test. It can be noted that the influence of voltage stress is modeled as linear, power law, and exponential equations, respectively for low voltage stress, medium voltage stress and high voltage stress. Another important observation is that the activation energy \(E_a\) is varying with voltage and temperature, especially under high voltage stress conditions.

IV. RELIABILITY-ORIENTED DESIGN FOR DC-LINKS

A. DC-Link Design Solutions

As the DC-link capacitors contribute to cost, size and failure of power electronic converters on a considerable scale [1], research efforts have been devoted to either optimal design of DC-link capacitor bank [30] or to the reduction of the DC-link requirement [31]. Fig. 8 shows the main types of DC-link design solutions. The most widely applied solution is the one shown in Fig. 8(a) by selecting Al-Caps or MPPF-Caps as discussed in §II. Recently, a hybrid design solution composed of both Al-Caps and MPPF-Caps is proposed in [32] as illustrated in Fig. 8(b). A DC-link with 40 mF Al-Caps bank and a 2 mF MPPF-Cap are selected for a 250 kW inverter, by taking the advantage of their different frequency characteristics. Fig. 9 compares the ripple current stresses in the Al-Caps bank with and without the additional 2 mF film capacitor. By adopting this solution, the reliability of the Al-Caps bank is to be improved due to reduced current stresses. Another research direction is to reduce the energy storage requirement in the DC-link so that Al-Caps could be replaced by MPPF-Caps to achieve higher level of reliability without considerably increase the cost and volume. For example, the concept of Fig. 8(c) is to synchronize the current \(i_{DC}\) and \(i_{DC2}\) by additional control scheme to reduce the ripple current flowing through the DC-link capacitor [33]. The concept of Figs. 8(d) and (e) is to introduce an additional ripple power port from the DC-link [31] and [34]. These two solutions could reduce the overall energy storage requirement of the DC-link as the study cases demonstrated in [31] and [34]. The advantage of the series voltage compensator solution is that the power capacity rating of the compensator is much lower than that of the parallel circuit shown in Fig. 8(d). It is due to very low voltage stresses on the active devices inside the compensator.

B. Reliability-Oriented Design Procedure for DC-Link

Besides the possibilities brought by innovative DC-link solutions, a reliability-oriented design procedure could provide further potentials to build the reliability into the DC-link. Fig. 10 presents a reliability-oriented design procedure for DC links. Highlighted areas indicate where further research efforts are expected.
System level specifications, mission profile and design constraints

Selection of converter topology and control scheme

DC link level: $V_D$, voltage ripple limit: $\Delta V_D$, cost limit: $Q_{max}$, lifetime limit: $L_{min}$, size limit $S_{max}$

Environmental stresses (e.g., ambient temperature, humidity level, etc.)

Selection of capacitor type for DC-link application: Al-Caps, MPPF-Caps or MLC-Caps

Select required voltage range

Select required capacitance from manufacturer’s data chart

$I_{C_{rms}} < I_{C_{rated}}$

$\frac{dV_D}{dt} < \left(\frac{dV_D}{dt}\right)_{max}$

$\frac{dI}{dt} < \left(\frac{dI}{dt}\right)_{max}$

Capacitor bank design

Hotspot temperature estimation

Active cooling

$T_{hotspot} < T_{hotspot,limit}$

Higher voltage range

Critical failure mechanisms and critical stressors

Failure rate models and lifetime models

Failure rate and lifetime prediction

$L > L_{min}$

Robustness analysis (design margin)

Optimization of reliability, robustness, cost and size

Compare with another solution

Yes

Optimized DC-link design

Highlighted area: Future research needs

Fig. 10. Reliability-oriented design procedure for capacitors in DC links.
V. CONDITION MONITORING OF DC-LINK CAPACITORS

Besides the lifetime prediction and reliability-oriented design, condition monitoring is another important action to improve the reliability of DC-link capacitors for critical applications. Of course condition monitoring may entail important investments in terms of devices, sensors and control scheme. All of them shall be evaluated in terms of cost related to the specific application. Table III shows the typical end-of-life criteria and degradation precursors for Al-Caps, MPPF-Caps, and MLC-Caps.

Impressive research work have been done on the condition monitoring of Al-Caps [35]-[39]. Fig. 11 shows the impedance characteristics of capacitors. In the low frequency range ($\omega < \omega_1$), the impedance is approximated to $\omega C$. In the medium frequency range ($\omega_1 < \omega < \omega_2$), the impedance is dominated by the ESR. Therefore, by extracting the voltage and/or current information in the respective frequency ranges, the capacitance and ESR can be estimated.

The main applied principle to estimate the capacitance and ESR is calculated by the residual generated by the difference between the measured capacitance and ESR can be estimated.

There are two main principles for ESR estimation: a) $\text{ESR} = \frac{V_C}{I_C}$ where $V_C$ and $I_C$ are the Root-Mean-Square (RMS) values of the capacitor voltage and capacitor current in the ohmic region (i.e. $\omega_1 < \omega < \omega_2$, typically 5 – 10 kHz) [35]-[37]. The case temperature of the capacitor is usually measured to compensate the temperature dependence of ESR. This method requires two band-pass filters, which should have sufficient bandwidth to extract the frequency components of interest. At the same time, the frequency components below $\omega_1$ shall be rejected sufficiently. b) $\text{ESR} = \frac{P_C}{I_C^2}$ where $P_C$ is the average power dissipated in the capacitor and $I_C$ is the RMS current of the capacitor [38]-[39]. This method does not require specific band-pass filters. The introduction of the sensor in the capacitor current path is not desirable due to its stray inductance.

**Table III. Typical End-of-Life Criteria and Condition Monitoring Parameters**

<table>
<thead>
<tr>
<th>Failure criteria</th>
<th>Al-Caps</th>
<th>MPPF-Caps</th>
<th>MLC-Caps</th>
</tr>
</thead>
<tbody>
<tr>
<td>C: 20% reduction ESR: 2 times</td>
<td>C: 5% reduction DF: 3 times</td>
<td>C: 10% reduction $R_p &lt; 10^7 \Omega$ DF: 2 times</td>
<td></td>
</tr>
<tr>
<td>Degradation precursors</td>
<td>C or ESR, or both</td>
<td>C</td>
<td>C, $R_p$</td>
</tr>
<tr>
<td>DF - Dissipation Factor; $R_p$ – insulation resistance.</td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

**CONCLUSIONS**

This paper gives an overview on the reliability aspects of three types of capacitors for DC-link applications in power electronics. Failure modes, failure mechanisms and lifetime models of the capacitors are briefly discussed. Reliability-oriented design approach and condition monitoring methods for DC-link capacitors are presented. Based on this literature review, the following challenges and suggested research directions are addressed:

**Challenges** – a) uncertainties in the mission profile of specific applications, which may lead to unrealistic component level stress analysis; b) variations of the constant parameters in lifetime models (e.g. activation energy, voltage acceleration factor) with external stresses, which require resource-consuming accelerated lifetime testing to investigate them and may not be economic viable to some extent; c) well established lifetime models take into account the stressors of voltage, ripple current and temperature only.

**Suggested Research directions** – a) real time capacitor electrical models that takes into account the operating points (e.g. voltage, ripple current, ambient temperature, frequency, time, etc.) which will contribute to more accurate stress analysis of DC-link capacitors; b) investigation into the coupling effect among various stressors on the lifetime of capacitors; c) the reliability of different DC-link solutions shall be strictly examined as new circuits or software algorithms are introduced which could be the new sources of failure; d) new non-invasive condition monitoring methods with less realization effort and higher estimation accuracy.

**REFERENCES**

